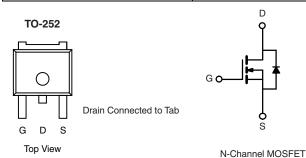


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Vishay Siliconix

Automotive N-Channel 55 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	55				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.020				
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.026				
I _D (A)	30				
Configuration	Single				



FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R_g and UIS Tested
- AEC-Q101 Qualifiedd
- Compliant to RoHS Directive 2002/95/EC



ORDERING INFORMATION	
Package	TO-252
Lead (Pb)-free and Halogen-free	SQD35N05-26L-GE3

PARAMETER PARAMETER	,	SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	55	
Gate-Source Voltage		V _{GS}	± 20	V
Continuous Drain Current	T _C = 25 °C ^a		30	
	T _C = 125 °C	- I _D	19	
Continuous Source Current (Diode Conduction) ^a		I _S	30	А
Pulsed Drain Current ^b		I _{DM}	120	
Single Pulse Avalanche Energy	0.4	I _{AS}	20	
Single Pulse Avalanche Current	L = 0.1 mH	E _{AS}	20	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	D	50	W
	T _C = 125 °C	P_{D}	16	VV
Operating Junction and Storage Temperatu	re Range	T _J , T _{stg}	- 55 to + 175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	60	°C/W
Junction-to-Case (Drain)		R_{thJC}	3	C/ VV

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		55	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$		2	2.5	\ \	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 55 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 55 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	1	-	50	μΑ	
		$V_{GS} = 0 V$	V _{DS} = 55 V, T _J = 175 °C	-	-	250		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 5 V	$V_{DS} \ge 5 V$	30	-	-	Α	
		V _{GS} = 10 V	I _D = 20 A	=	0.016	0.020	Ω	
Durin Con our Con Olate Brainlean 3	ь	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.035		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.043		
		V _{GS} = 4.5 V	I _D = 15 A	-	0.021	0.026		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		-	34	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			=	938	1175	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	203	255		
Reverse Transfer Capacitance	C _{rss}]		=	86	110		
Total Gate Charge ^c	Qg			-	12	18		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 5 V$	$V_{DS} = 25 \text{ V}, I_D = 35 \text{ A}$	-	4.1	-	nC	
Gate-Drain Charge ^c	Q _{gd}	1		-	4.8	-		
Gate Resistance	R _g		f = 1 MHz		2.6	4	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	7	11		
Rise Time ^c	t _r	V_{DD} = 25 V, R_L = 0.71 Ω $I_D \cong$ 35 A, V_{GEN} = 10 V, R_g = 1 Ω		-	10	15	- ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	18	27		
Fall Time ^c	t _f			-	5	8		
Source-Drain Diode Ratings and Char-	acteristics ^b	*						
Pulsed Current ^a	I _{SM}			-	-	120	Α	
Forward Voltage	V _{SD}	I _F = 80 A, V _{GS} = 0 V			1.2	1.5	V	

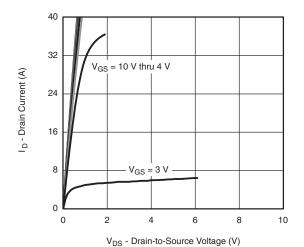
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

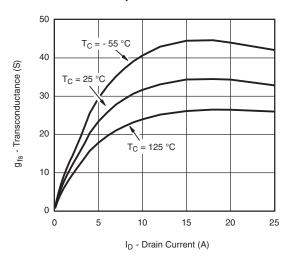
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



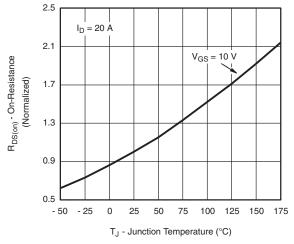
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



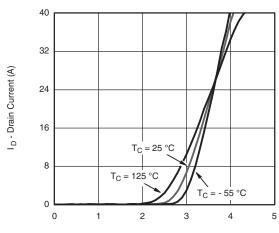
Output Characteristics



Transconductance

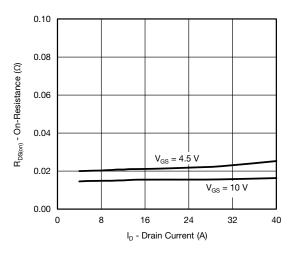


On-Resistance vs. Junction Temperature

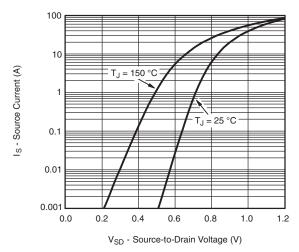


V_{GS} - Gate-to-Source Voltage (V)

Transfer Characteristics



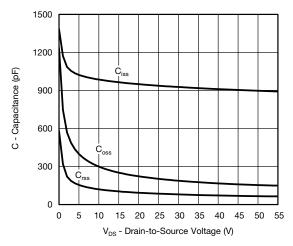
On-Resistance vs. Drain Current



Source Drain Diode Forward Voltage

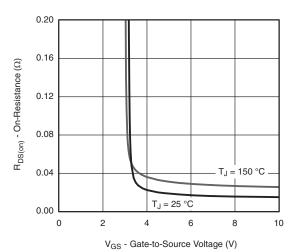


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

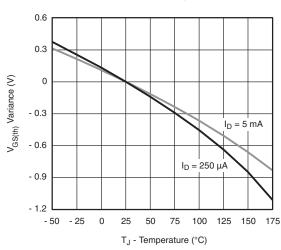


6

Capacitance

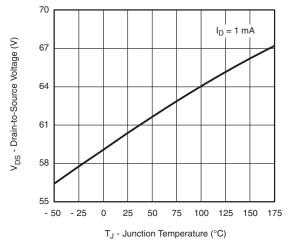


Gate Charge



On-Resistance vs. Gate-to-Source Voltage

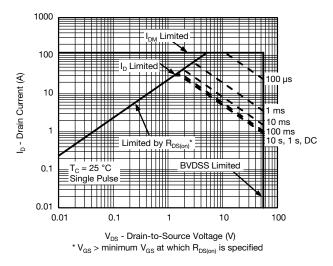
Threshold Voltage



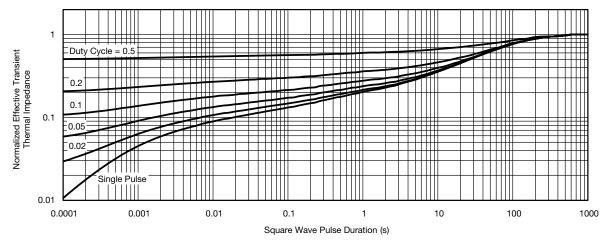
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



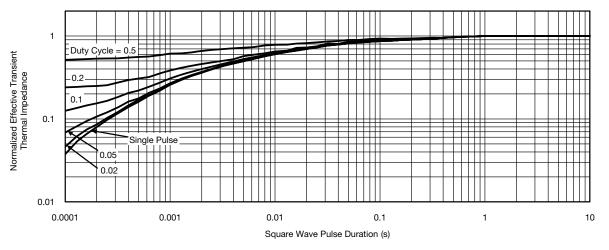
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



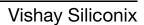
Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

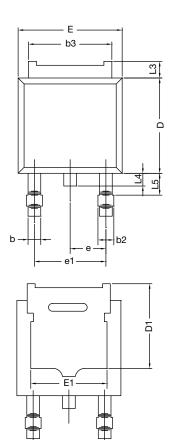
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

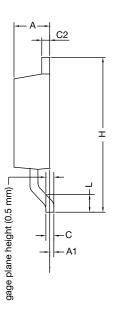
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?68839.





TO-252AA Case Outline



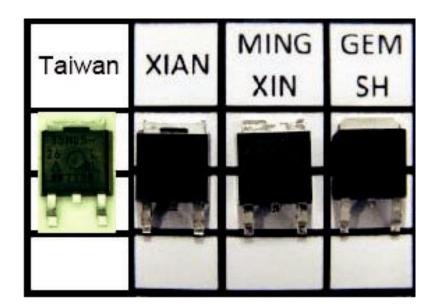


	MILLIN	METERS	INC	HES		
DIM.	MIN.	MAX.	MIN.	MAX.		
Α	2.18	2.38	0.086	0.094		
A1	-	0.127	-	0.005		
b	0.64	0.88	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215		
С	0.46	0.61	0.018	0.024		
C2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245		
D1	4.10	-	0.161	-		
Е	6.35	6.73	0.250	0.265		
E1	4.32	-	0.170	-		
Н	9.40	10.41	0.370	0.410		
е	2.28	BSC	0.090	BSC		
e1	4.56	BSC	0.180 BSC			
L	1.40	1.78	0.055	0.070		
L3	0.89	1.27	0.035	0.050		
L4	=	1.02	-	0.040		
L5	1.01	1.52	0.040	0.060		
ECN: T13-0359-Rev. O, 03-Jun-13						

DWG: 5347

Notes

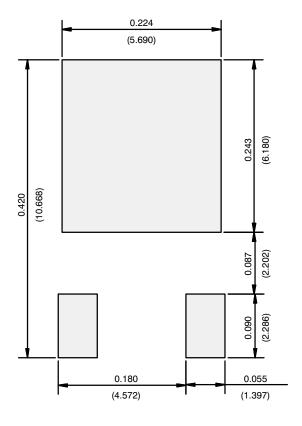
- Dimension L3 is for reference only.
- Xi'an, Mingxin, and GEM SH actual photo.



Revision: 03-Jun-13 Document Number: 71197



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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Revision: 02-Oct-12 Document Number: 91000